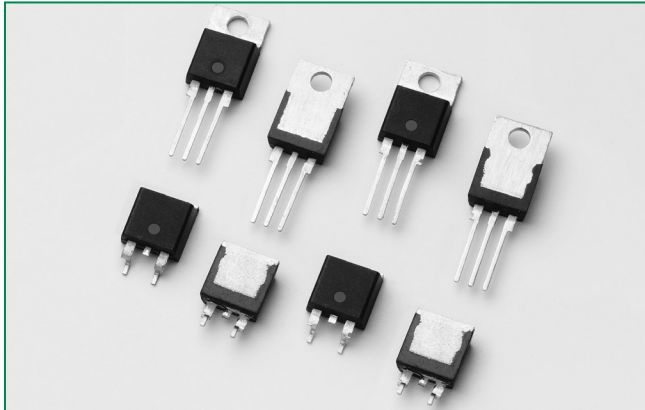


**SVxx12xx series**



**Description**

This SVxx12xx high junction temperature SCR series is ideal for uni-directional switch applications such as phase control in heating, motor speed controls, converters/rectifiers, inrush current control and capacitive discharge ignitions.

These SCRs have a low gate current trigger level of 6mA, 10mA maximum at approximately 1.5V.

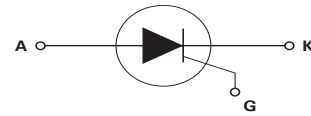
**Features & Benefits**

- Halogen free and RoHS compliant
- Surge capability up to 120 A at 60 Hz half cycle
- 150°C maximum junction temperature
- High dv/dt performance

**Main Features**

Symbol	Value	Unit
$I_{T(RMS)}$	12	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT}$	6 to 10	mA

**Schematic Symbol**



**Applications**

Typical applications include AC Generator (ACG) rectifiers, battery voltage regulators and generic converters and inrush current controller in various AC to DC applications. Additional applications include controls for power tools, home/brown good and white goods appliances.

Internally constructed isolated packages offered for ease of heat sinking with high isolation voltage.

**Absolute Maximum Ratings**

Symbol	Parameter	Test Conditions	Value	Unit
$V_{DSM}/V_{RSM}$	Peak non-repetitive blocking voltage	PW=100 $\mu$ s	800	V
$I_{T(RMS)}$	RMS on-state current	SVxx12Lx $T_c = 110^\circ\text{C}$	12	A
		SVxx12Rx SVxx12Nx $T_c = 135^\circ\text{C}$		
$I_{T(AV)}$	Average on-state current	SVxx12Lx $T_c = 110^\circ\text{C}$	7.6	A
		SVxx12Rx SVxx12Nx $T_c = 135^\circ\text{C}$		
$I_{TSM}$	Peak non-repetitive surge current (single half cycle, $T_j$ (initial) = 25°C)	$f = 50\text{Hz}$	100	A
		$f = 60\text{Hz}$	120	
$I^2t$	$I^2t$ Value for fusing	$t_p = 8.3 \text{ ms}$	60	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current	$f = 60\text{Hz}; T_j = 150^\circ\text{C}$	100	A/ $\mu$ s
$I_{GM}$	Peak gate current	$T_j = 150^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 150^\circ\text{C}$	0.8	W
$T_{stg}$	Storage temperature range		-40 to 150	°C
$T_j$	Operating junction temperature range		-40 to 150	

Note: xx=voltage/10, x=sensitivity

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

Symbol	Test Conditions		SVxx12x1	SVxx12x2	Unit
$I_{GT}$	$V_D = 12V$ $R_L = 60\ \Omega$	MAX.	6	10	mA
		MIN.	2	5	
$V_{GT}$	$V_D = 12V$ $R_L = 60\ \Omega$	MAX.	1.5	1.5	V
dv/dt	$V_D = 67\% V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$	MIN.	400	800	V/ $\mu\text{s}$
	$V_D = 67\% V_{DRM}$ ; gate open; $T_J = 150^\circ\text{C}$		200	400	
$V_{GD}$	$V_D = V_{DRM}$ $R_L = 3.3\ \text{k}\Omega$ $T_J = 125^\circ\text{C}$	MIN.	0.2	0.2	V
$I_H$	$I_T = 200\text{mA}$ (initial)	MAX.	22	35	mA
$t_q$	$I_T = 2\text{A}$ ; $t_p = 50\ \mu\text{s}$ ; dv/dt = 5V/ $\mu\text{s}$ ; di/dt = 30A/ $\mu\text{s}$	MAX.	25	25	$\mu\text{s}$
$t_{gt}$	$I_G = 2 \times I_{GT}$ PW = 15 $\mu\text{s}$ $I_T = 24\text{A}$	TYP.	2.6	2.6	$\mu\text{s}$

Note: xx=voltage/10, x=package

### Static Characteristics

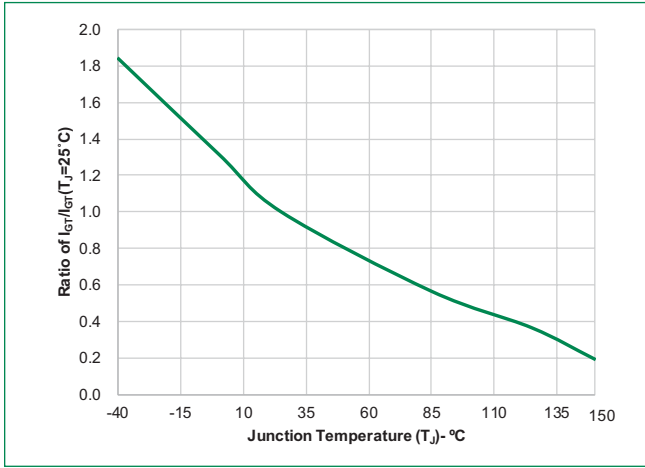
Symbol	Test Conditions		Value	Unit	
$V_{TM}$	Component $I_T = 24\text{A}$ ; $t_p = 380\ \mu\text{s}$	MAX.	1.6	V	
$I_{DRM} / I_{RRM}$	$V_{DRM} = V_{RRM}$	$T_J = 25^\circ\text{C}$	MAX.	10	$\mu\text{A}$
		$T_J = 125^\circ\text{C}$		500	
		$T_J = 150^\circ\text{C}$		2000	

### Thermal Resistances

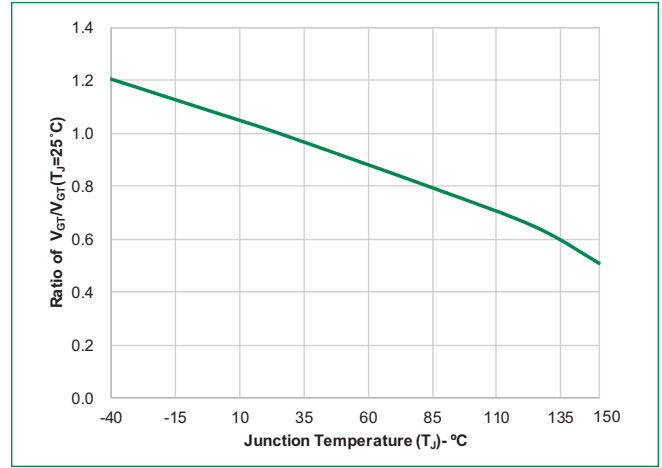
Symbol	Parameter	Value	Unit
$R_{\theta(JC)}$	Junction to case (AC)	SVxx12Lx	2.5
		SVxx12Rx SVxx12Nx	1.1

Note: xx=voltage/10, x=sensitivity

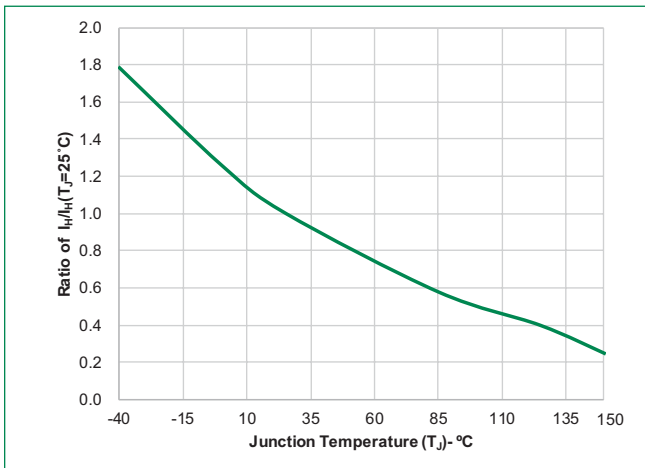
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



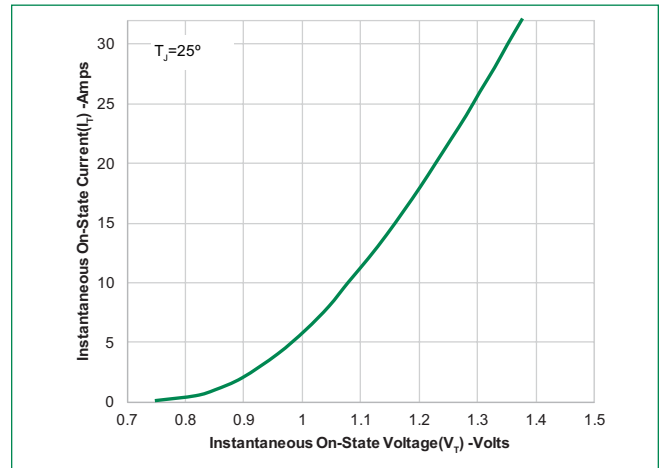
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



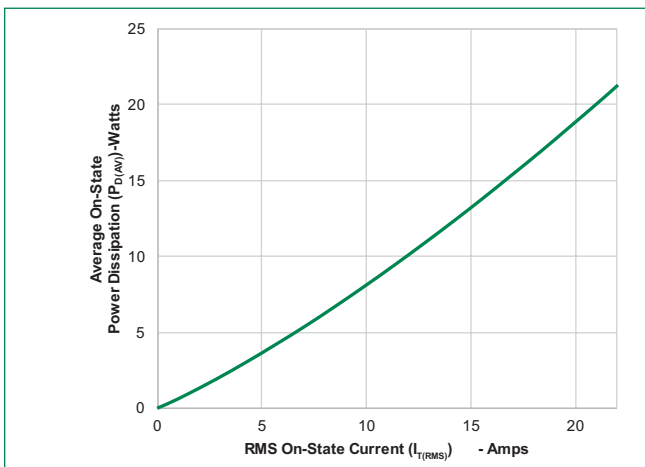
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



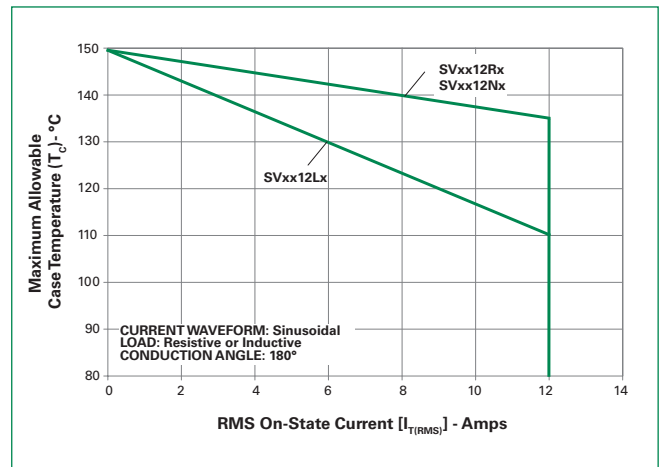
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



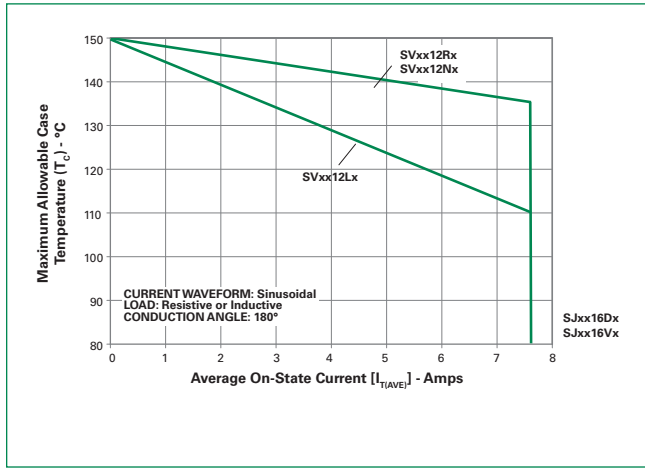
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



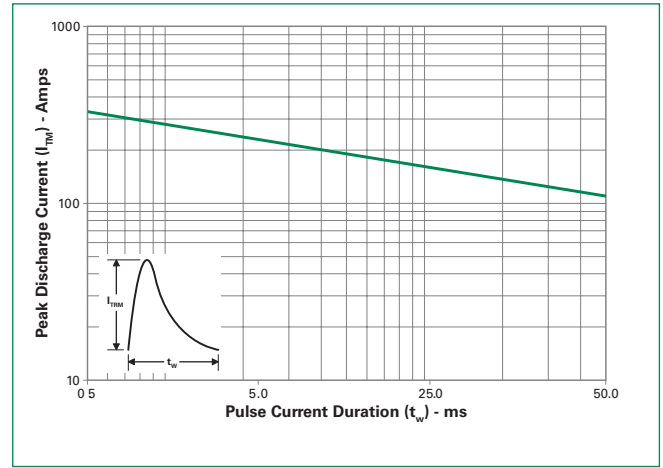
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current**



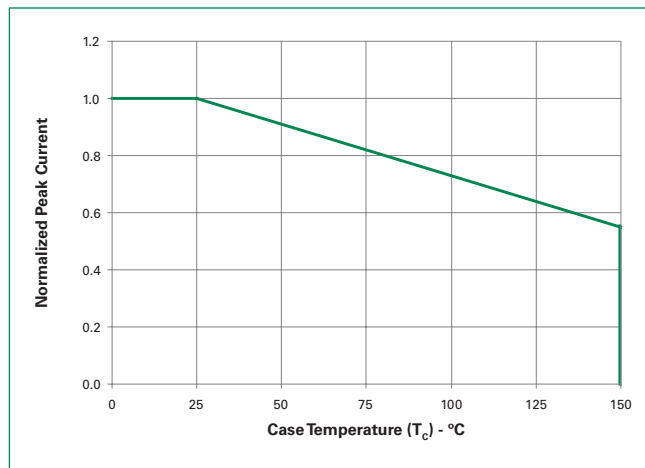
**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



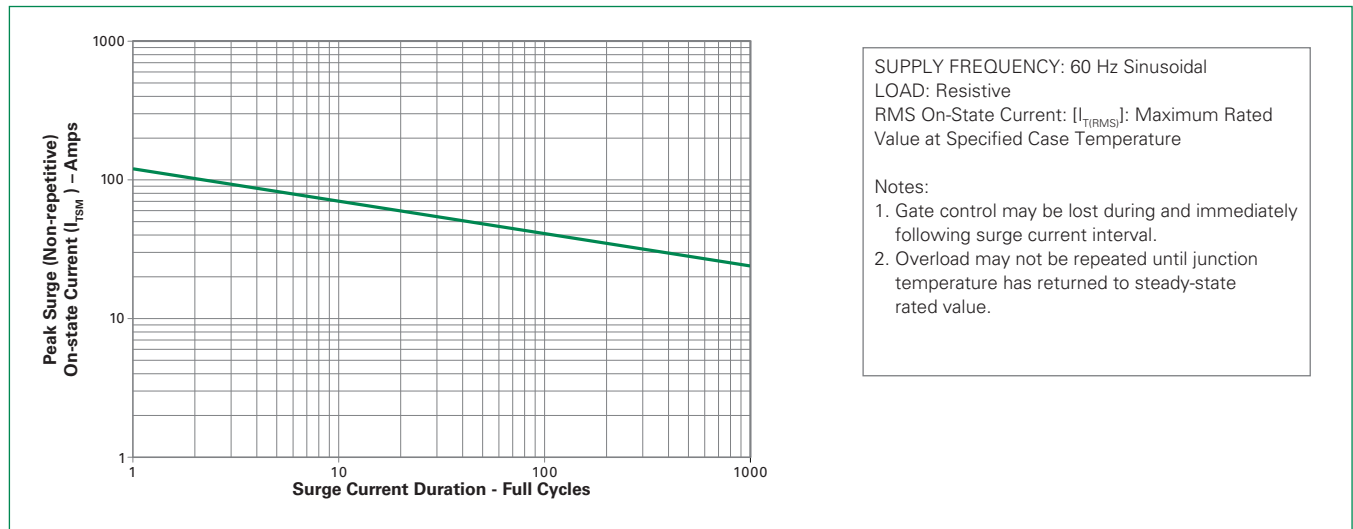
**Figure 8: Peak Capacitor Discharge Current**



**Figure 9: Peak Capacitor Discharge Current Derating**

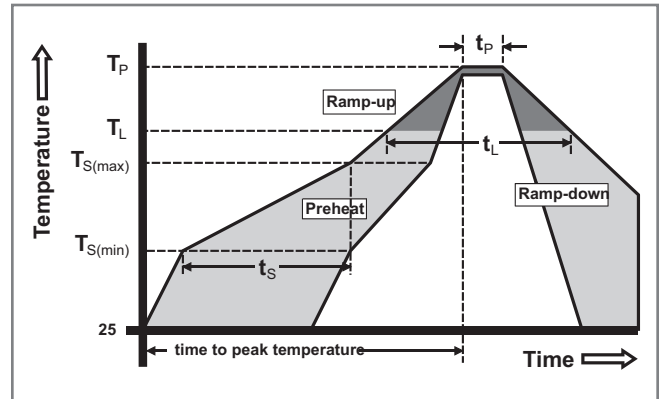


**Figure 10: Surge Peak On-State Current vs. Number of Cycles**



**Soldering Parameters**

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 180 secs
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		5°C/second max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		5°C/second max
Reflow	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Time ( $t_L$ )	60 – 150 seconds
Peak Temperature ( $T_p$ )		260 <sup>+0/-5</sup> °C
Time within 5°C of actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_p$ )		8 minutes Max.
Do not exceed		280°C



**Physical Specifications**

<b>Terminal Finish</b>	100% Matte Tin-plated
<b>Body Material</b>	UL Recognized compound meeting flammability rating V-0
<b>Lead Material</b>	Copper Alloy

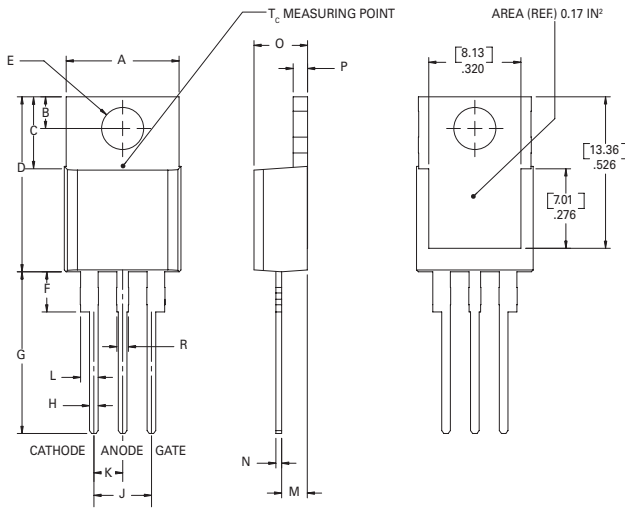
**Design Considerations**

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

**Environmental Specifications**

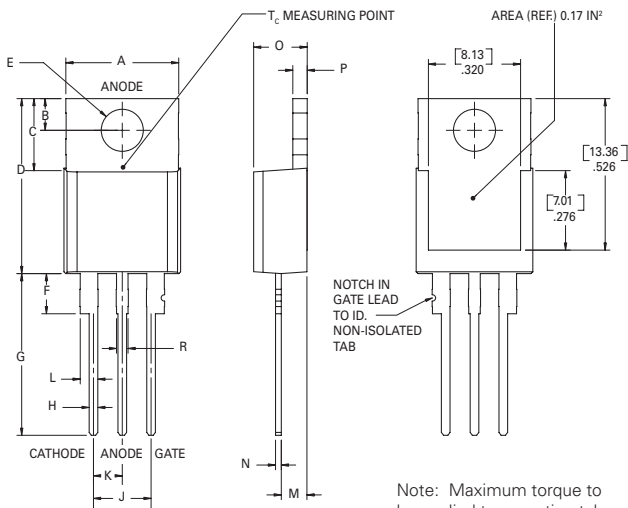
Test	Specifications and Conditions
<b>AC Blocking</b>	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours
<b>Temperature Cycling</b>	MIL-STD-750, M-1051, 100 cycles; -55°C to +150°C; 15-min dwell-time
<b>Temperature/Humidity</b>	EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity
<b>High Temp Storage</b>	MIL-STD-750, M-1031, 1008 hours; 150°C
<b>Low-Temp Storage</b>	1008 hours; -40°C
<b>Resistance to Solder Heat</b>	MIL-STD-750 Method 2031
<b>Solderability</b>	ANSI/J-STD-002, category 3, Test A
<b>Lead Bend</b>	MIL-STD-750, M-2036 Cond E
<b>Moisture Sensitivity Level</b>	Level 1, JEDEC-J-STD-020D

### Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

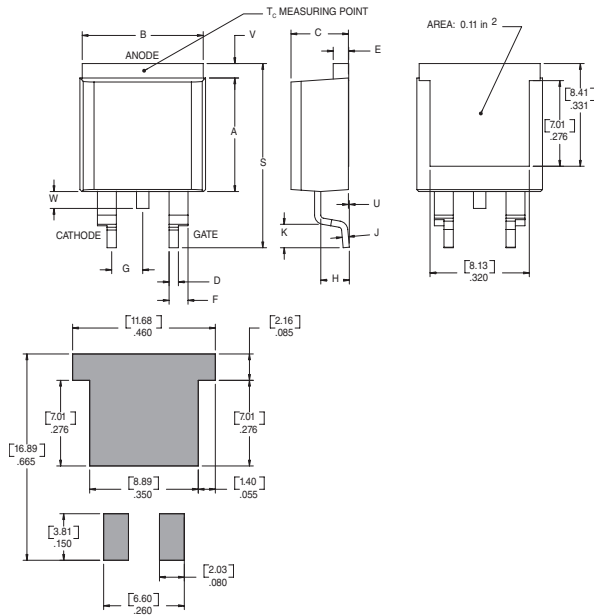
### Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

**Dimensions — TO- 263AB (N-package) — D<sup>2</sup>-Pak Surface Mount**



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.360	0.370	9.14	9.40
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
E	0.045	0.060	1.14	1.52
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
H	0.092	0.102	2.34	2.59
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.88
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.02	1.78

**Product Selector**

Part Number	Voltage	Gate Sensitivity	Type	Package
	600V			
SVxx12L1	X	6mA	Standard SCR	TO-220L
SVxx12R1	X	6mA	Standard SCR	TO-220R
SVxx12N1	X	6mA	Standard SCR	TO-263
SVxx12L2	X	10mA	Standard SCR	TO-220L
SVxx12R2	X	10mA	Standard SCR	TO-220R
SVxx12N2	X	10mA	Standard SCR	TO-263

Note: xx = Voltage/10